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Features

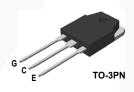
- Maximum Junction Temperature: T_J = 175^oC
- · Positive Temperature Co-efficient for Easy Parallel Operating
- · High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 1.33 V (Typ.) @ I_C = 40 A
- 100% of the Parts tested for I_{LM}(1)
- · High Input Impedance
- · Fast Switching
- · Tighten Parameter Distribution
- · RoHS Compliant

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 4th generation IGBTs offer superior conduction and switching performance and easy parallel operation. This device is well suited for the resonant or soft switching application such as induction heating and MWO.

Applications

· Induction Heating, MWO





Absolute Maximum Ratings

Symbol	Description	1	FGA40T65UQDF	Unit
V _{CES}	Collector to Emitter Voltage		650	V
V _{GES}	Gate to Emitter Voltage		± 20	V
	Transient Gate to Emitter Voltage		± 30	V
I _C	Collector Current	@ T _C = 25 ^o C	80	А
ιC	Collector Current	@ T _C = 100°C	40	A
I _{LM} (1)	Pulsed Collector Current	@ T _C = 25°C	120	A
I _{CM} (2)	Pulsed Collector Current		120	А
I _F	Diode Forward Current	@ T _C = 25°C	40	A
	Diode Forward Current	@ T _C = 100°C	20	A
I _{FM}	Pulsed Diode Maximum Forward Cur	60	А	
PD	Maximum Power Dissipation	@ T _C = 25°C	231	W
' D	Maximum Power Dissipation	@ T _C = 100°C	115	W
TJ	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 secon	300	°C	

Notes:

1. V_{CC} = 400 V, V_{GE} = 15 V, I_C = 120 A, R_G = 20 Ω , Inductive Load 2. Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	FGA40T65UQDF	Unit	
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case, Max.	0.65	°C/W	
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case, Max.	1.75	°C/W	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	40	°C/W	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Qty per Tube
FGA40T65UQDF	FGA40T65UQDF	TO-3PN	-	-	30

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA	650	-	-	V
ΔBV _{CES} / ΔT _J	Temperature Coefficient of Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA	-	0.52	-	V/ºC
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$		-	250	μA
I _{GES}	G-E Leakage Current	V_{GE} = V_{GES} , V_{CE} = 0 V	-	-	± 400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 40 mA, V _{CE} = V _{GE}	2.5	4.0	5.5	V
- (- /		I _C = 40 A, V _{GE} = 15 V	-	1.33	1.67	V
V _{CE(sat)} Collector to Emitter Saturation Voltage		$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 175^{\circ}\text{C}$	-	1.5	-	V
Dynamic C	haracteristics					
C _{ies}	Input Capacitance		-	7309	-	pF
C _{oes}	Output Capacitance	V _{CE} = 30 V _, V _{GE} = 0 V, f = 1 MHz	-	58	-	pF
C _{res}	Reverse Transfer Capacitance			30	-	pF
Switching	Characteristics					
T _{d(on)}	Turn-On Delay Time		-	32	- /	ns
T _r	Rise Time		-	18	-	ns
T _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 40 A,	-	271	-	ns
T _f	Fall Time	R _G = 6 Ω, V _{GE} = 15 V,	-	11		ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	989	- /	μJ
E _{off}	Turn-Off Switching Loss		-	310	-	μJ
E _{ts}	Total Switching Loss		-	1299	-	μJ
T _{d(on)}	Turn-On Delay Time		-	30	-	ns
T _r	Rise Time		-	22	-	ns
T _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 40 A,	-	298	-	ns
T _f	Fall Time	$R_{G} = 6 \Omega, V_{GE} = 15 V,$	-	16	-	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 175°C	-	1400	-	μJ
E _{off}	Turn-Off Switching Loss]	-	553	-	μJ
E _{ts}	Total Switching Loss]	-	1953	-	μJ

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Electrical Characteristics of the IGBT (Continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Qg	Total Gate Charge		-	306	-	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 40 A, V _{GE} = 15 V	-	30	-	nC
Q _{gc}	Gate to Collector Charge	VGE - 13 V	-	77	-	nC

Electrical Characteristics of the Diode T_C = 25°C unless otherwise noted

Symbol	Parameter		Test Conditio	ns	Min.	Тур.	Max.	Unit
V _{FM} Diode	Diode Forward Voltage	I _F = 2	20 A	T _C = 25°C	-	1.5	1.95	V
	Diodo i olivara voltago			T _C = 175°C	-	1.39	-	
E _{rec}	Reverse Recovery Energy			T _C = 175 ^o C	-	115	-	μJ
T _{rr}	Diode Reverse Recovery Time		20 A, dI _F /dt = 200 A/µs	T _C = 25°C	-	89	-	ns
· IT	Didde Reverse Recovery Time	$ _{1}^{1} = 20 \text{ A}, \text{ alp/at} = 200 \text{ A}/\mu$	T _C = 175°C	- 1	251	-		
Q _{rr}	Diode Reverse Recovery Charge]		T _C = 25 ^o C	-	289	-	nC
~11	Diede Hereice Hereich, endige			T _C = 175 ^o C	-	1502	-	

Figure 1. Typical Output Characteristics 120 120 $T_{C} = 25^{\circ}C$ 20V 15V 12V 10V Collector Current, I_c [A] Collector Current, Ic [A] 90 90 $V_{GE} = 8V$ 60 60 30 30 0 0 0 2 3 0 Collector-Emitter Voltage, V_{CE} [V] **Figure 3. Typical Saturation Voltage** Characteristics 2.0 120 Common Emitter V_{GE} = 15V $T_{C} = 25^{\circ}C$ — Collector Current, Ic [A] 90 T_C = 175^oC 1.5 60

Typical Performance Characteristics

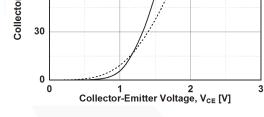


Figure 5. Saturation Voltage vs. V_{GE}

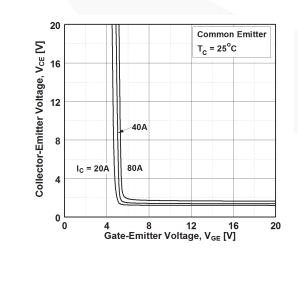
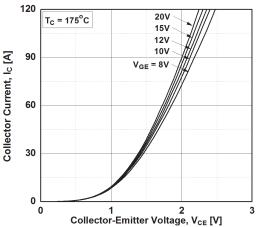
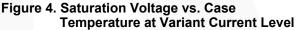


Figure 2. Typical Output Characteristics





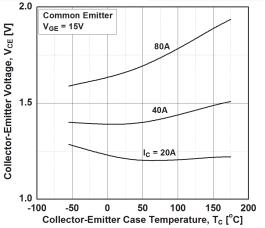
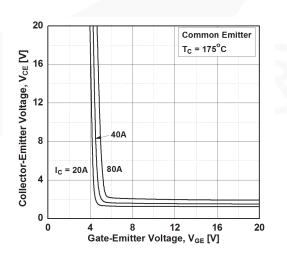


Figure 6. Saturation Voltage vs. V_{GE}



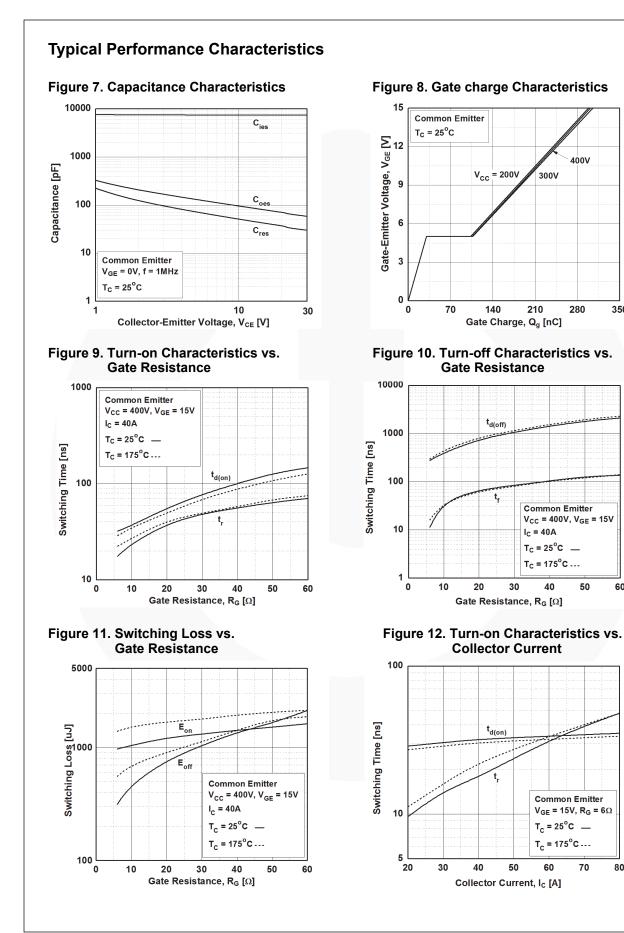
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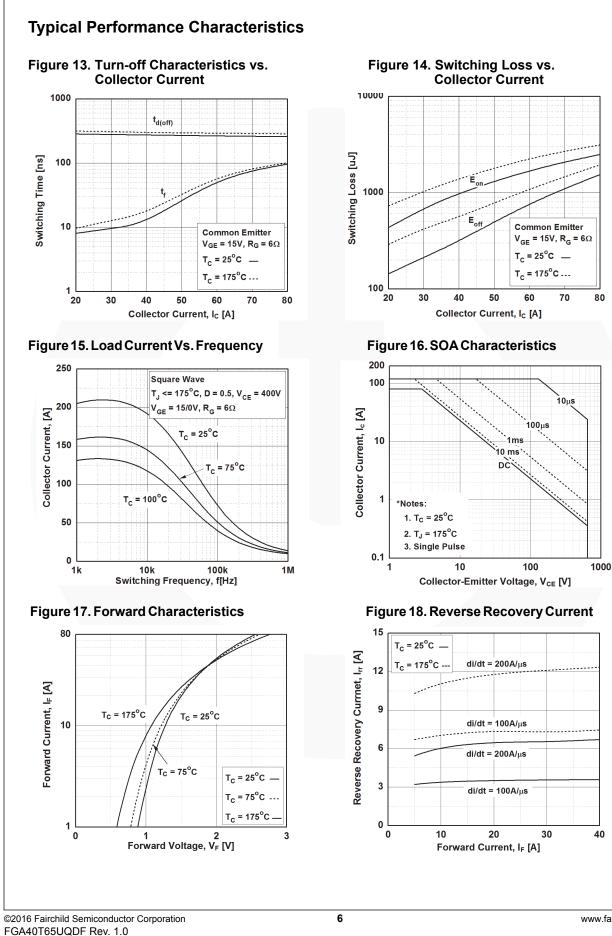
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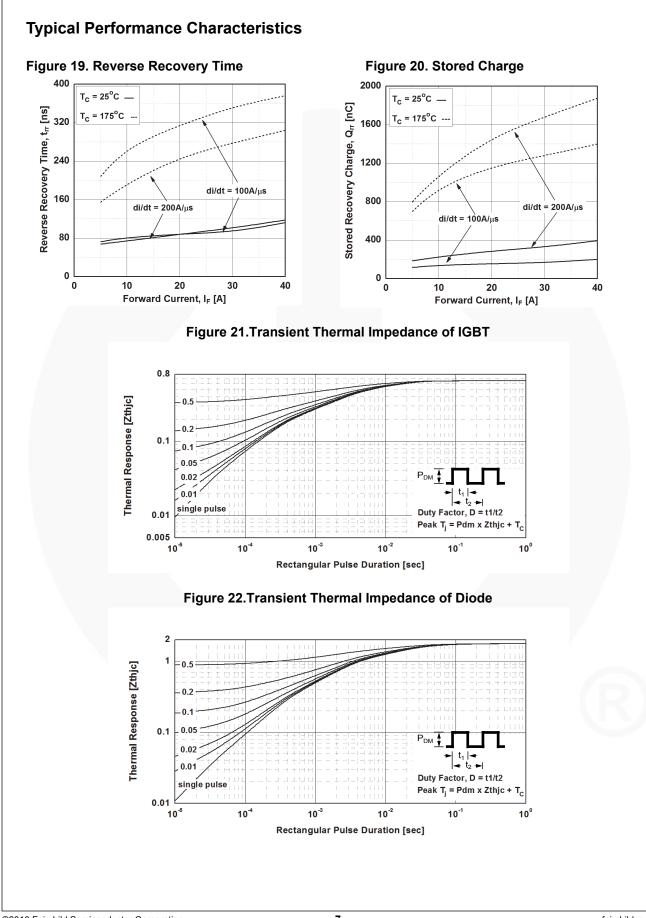
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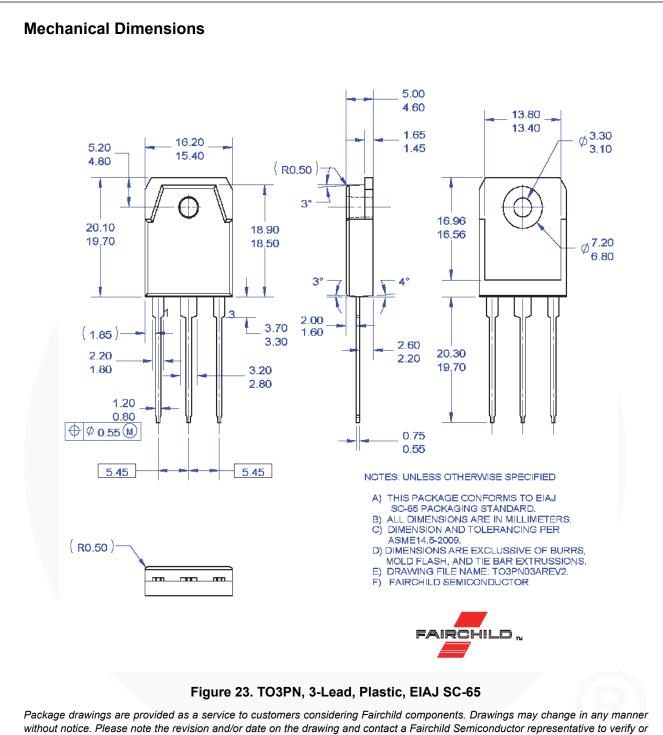


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FGA40T65UQDF — 650 V, 40 A Field Stop Trench IGBT



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